	Application No.	Applicant(s)	
	10/751,208	HUAJIE CHEN	
Notice of Allowability	Examiner	Art Unit	
	Thanh Y. Tran	2822	
The MAILING DATE of this communication app. All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85 NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT R of the Office or upon petition by the applicant. See 37 CFR 1.313	s (OR REMAINS) CLOSED in this app) or other appropriate communication BIGHTS. This application is subject to	plication. If <mark>not include</mark> will be mailed in due o	ed course. THIS
1. This communication is responsive to			
2. The allowed claim(s) is/are 1-20.			
3. \boxtimes The drawings filed on $\underline{6/18/04}$ are accepted by the Examir	ner.		
 4. ☐ Acknowledgment is made of a claim for foreign priority u a) ☐ All b) ☐ Some* c) ☐ None of the: 1. ☐ Certified copies of the priority documents have 2. ☐ Certified copies of the priority documents have 3. ☐ Copies of the certified copies of the priority do International Bureau (PCT Rule 17.2(a)). * Certified copies not received: 	e been received. e been received in Application No		ion from the
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONN THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		complying with the req	uirements
5. A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which giv	nitted. Note the attached EXAMINER res reason(s) why the oath or declara	'S AMENDMENT or Nation is deficient.	OTICE OF
6. CORRECTED DRAWINGS (as "replacement sheets") mu	st be submitted.		
(a) including changes required by the Notice of Draftspers		948) attached	
1) 🔲 hereto or 2) 🔲 to Paper No./Mail Date	-: -:		
(b) including changes required by the attached Examiner Paper No./Mail Date	's Amendment / Comment or in the C	Office action of	
Identifying Indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in the same of	1.84(c)) should be written on the drawir the header according to 37 CFR 1.121(ngs in th e front (not the d).	back) of
 DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT 			lote the
Attachment(s) 1. ☑ Notice of References Cited (PTO-892) 2. ☑ Notice of Draftperson's Patent Drawing Review (PTO-948)	5. ☐ Notice of Informal P 6. ☐ Interview Summary	(PTO-413),)-152)
3. Information Disclosure Statements (PTO-1449 or PTO/SB/0	Paper No./Mail Dat 08), 7. ☐ Examiner's Amendr	ment/Comment	
Paper No./Mail Date <u>01/02/04</u> 4. ☐ Examiner's Comment Regarding Requirement for Deposit	8. X Examiner's Stateme	ent of Reasons for Allo	wance
of Biological Material	9. Other		
	SUPERVISO:	IR ZARABIAN RY PATENT EVANMER OGY CENTER 2800	}

DETAILED ACTION

Allowable Subject Matter

- 1. Claims 1-20 are allowed.
- 2. The following is a statement of reasons for the indication of allowable subject matter:

Claim 1 recites, inter alia, "a method of forming an epitaxial silicon-containing layer on a silicon germanium surface, the method comprising the steps of: performing an ex-situ chemical oxide removal process on the silicon germanium surface so as to partially remove oxygen from the silicon germanium surface and leave a first amount of oxygen on the silicon germanium surface; and heating the silicon germanium surface sufficiently to remove additional oxygen from the silicon germanium surface and leave a second amount of oxygen, less than the first amount, on the silicon germanium surface"; and in the combination with other claimed limitations.

Claims 10 and 20 recite, inter alia, "a method of forming an epitaxial silicon-containing layer on a silicon germanium surface, the method comprising the steps of: performing an ex-situ chemical oxide removal process on the silicon surface so as to partially remove oxygen from the silicon surface and leave a first amount of oxygen on the silicon surface; and heating the silicon surface sufficiently to remove additional oxygen from the silicon surface and leave a second amount of oxygen, less than the first amount, on the silicon surface"; and in the combination with other claimed limitations.

The prior art of record does not teach or render obvious to modify the art of record so as to include the above mentioned-limitations.

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Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Contact Information

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thanh Y. Tran whose telephone number is (571) 272-2110. The examiner can normally be reached on M-F (9-6:30pm).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Amir Zarabian can be reached on (571) 272-1852. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published applications

may be obtained from either Private PAIR or Public PAIR. Status information for unpublished

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system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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